



LOW-VOLTAGE QUADRUPLE BUS SWITCH

IDT74CBTLV3126

FEATURES

- Pin-Out Compatible with Standard '126 Logic Products
- 5Ω A/B bi-directional switch
- Isolation Under Power-Off Conditions
- Over-voltage tolerant
- Latch-up performance exceeds 100mA
- Vcc = 2.3V - 3.6V, normal range
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- Output Enable, Active High
- Available in TSSOP and QSOP packages

APPLICATIONS:

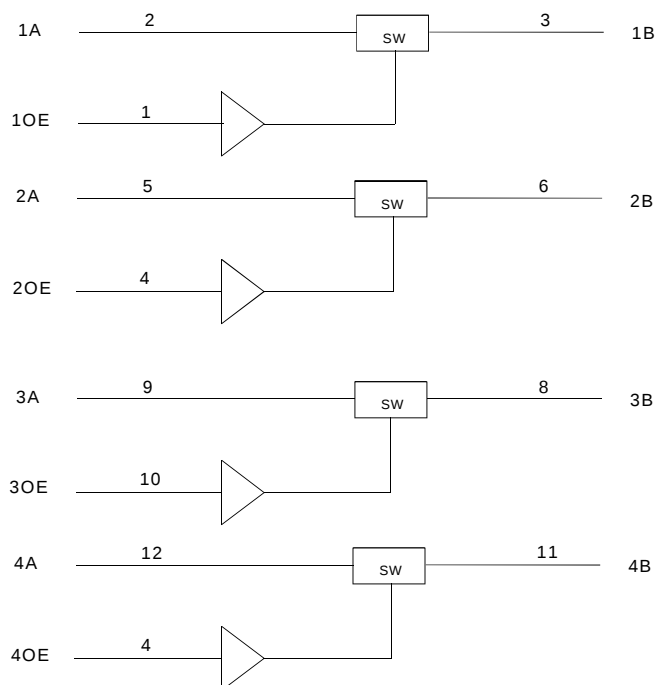
- 3.3V High Speed Bus Switching and Bus Isolation

DESCRIPTION:

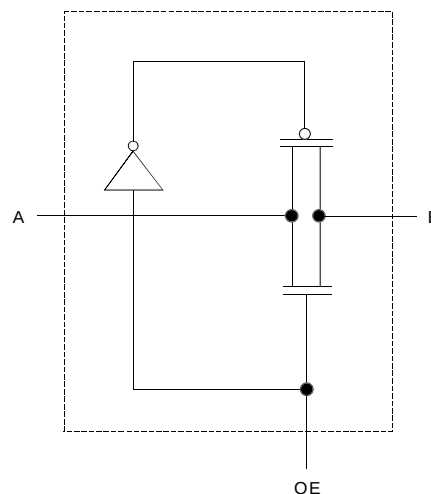
The CBTLV3126 features four independent switches. Each switch is enabled when the associated output-enable (OE) input is high.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTIONAL BLOCK DIAGRAM



SIMPLIFIED SCHEMATIC, EACH SWITCH



NOTE:

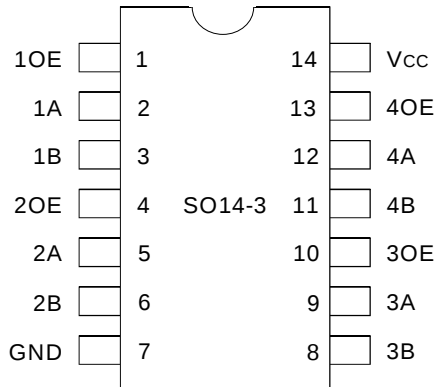
1. Pin numbers shown apply to the 14-pin TSSOP package.

The IDT logo is a registered trademark of Integrated Device Technology, Inc.

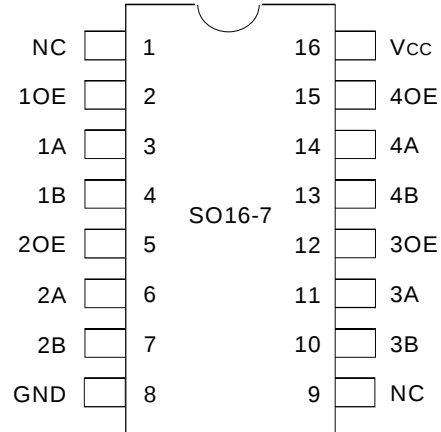
INDUSTRIAL TEMPERATURE RANGE

MARCH 2001

PIN CONFIGURATION



TSSOP
TOP VIEW



QSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
V _{CC}	Supply Voltage Range	−0.5 to 4.6	V
V _I	Input Voltage Range	−0.5 to 4.6	V
	Continuous Channel Current	128	mA
I _{IK}	Input Clamp Current, V _{I/O} < 0	−50	mA
T _{STG}	Storage Temperature	−65 to +150	°C

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE (1)

Input OE	Inputs/Outputs
H	A Port = B Port
L	Disconnect

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level

OPERATING CHARACTERISTICS, T_A = 25°C

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V _{CC}	Supply Voltage		2.3	3.6	V
V _{IH}	High-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	1.7	—	V
		V _{CC} = 2.7V to 3.6V	2	—	
V _{IL}	Low-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	—	0.7	V
		V _{CC} = 2.7V to 3.6V	—	0.8	
T _A	Operating Free-Air Temperature		−40	85	°C

NOTE:

- All unused control inputs of the device must be held at V_{CC} or GND to ensure proper operation of the device.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IK}	Control Inputs, Data I/O	$V_{CC} = 3\text{V}$, $I_I = -18\text{mA}$		—	—	-1.2	V
I_I	Control Inputs, Data I/O	$V_{CC} = 3.6\text{V}$, $V_I = V_{CC}$ or GND		—	—	± 1	μA
I_{OZ}	Data I/O	$V_{CC} = 3.6\text{V}$, $V_O = 0$ or 3.6V , switch disabled		—	—	5	μA
I_{OFF}		$V_{CC} = 0$, V_I or $V_O = 0$ to 3.6V		—	—	50	μA
I_{CC}		$V_{CC} = 3.6\text{V}$, $I_O = 0$, $V_I = V_{CC}$ or GND		—	—	10	μA
$\Delta I_{CC}^{(2)}$	Control Inputs	$V_{CC} = 3.6\text{V}$, One input at 3V , Other inputs at V_{CC} or GND		—	—	300	μA
C_I	Control Inputs	$V_I = 3\text{V}$ or 0		—	4	—	pF
$C_{IO(OFF)}$		$V_O = 3\text{V}$ or 0 , $OE = \text{GND}$		—	6	—	pF
$R_{ON}^{(3)}$	Max at $V_{CC} = 2.3\text{V}$ Typ at $V_{CC} = 2.5\text{V}$	$V_I = 0$	$I_O = 64\text{mA}$	—	5	8	Ω
			$I_O = 24\text{mA}$	—	5	8	
		$V_I = 1.7\text{V}$	$I_O = 15\text{mA}$	—	27	40	
	$V_{CC} = 3\text{V}$	$V_I = 0$	$I_O = 64\text{mA}$	—	5	7	
			$I_O = 24\text{mA}$	—	5	7	
		$V_I = 2.4\text{V}$	$I_O = 15\text{mA}$	—	10	15	

NOTES:

- Typical values are at 3.3V , $+25^{\circ}\text{C}$ ambient.
- The increase in supply current is attributable to each input that is at the specified voltage level rather than V_{CC} or GND.
- This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

Symbol	Parameter	$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		Unit
		Min.	Max.	Min.	Max.	
$t_{PD}^{(1)}$	Propagation Delay A to B or B to A	—	0.15	—	0.25	ns
t_{EN}	Output Enable Time OE to A or B	1	4.5	1	4.2	ns
t_{DIS}	Output Disable Time OE to A or B	1	4.7	1	4.8	ns

NOTE:

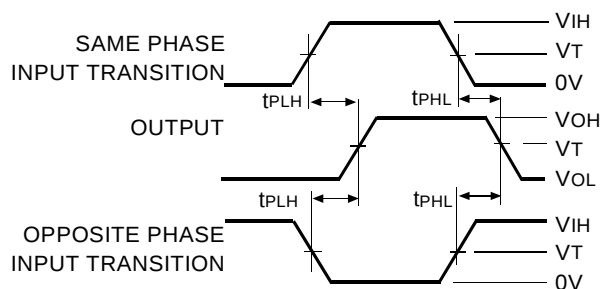
- The propagation time is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).

TEST CIRCUITS AND WAVEFORMS

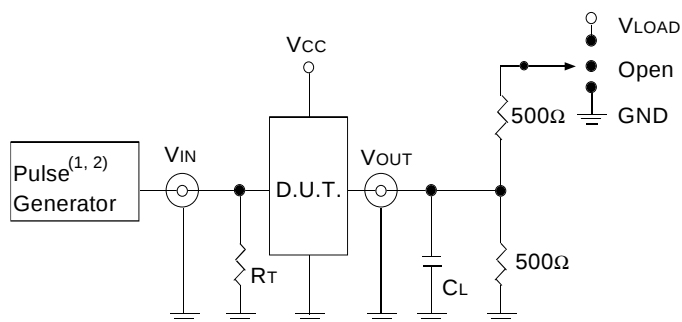
TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
V_{LOAD}	6	$2 \times V_{CC}$	V
V_{IH}	3	V_{CC}	V
V_T	1.5	$V_{CC}/2$	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF

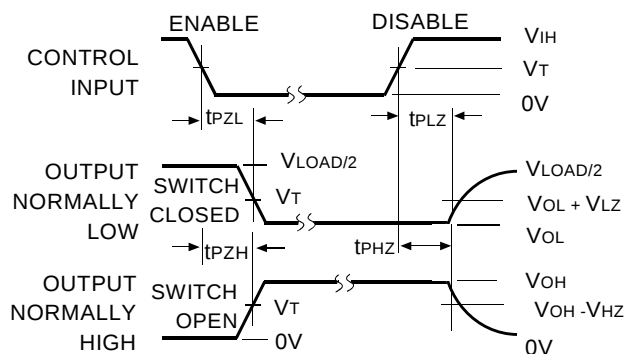
PROPAGATION DELAY



TEST CIRCUITS FOR ALL OUTPUTS



ENABLE AND DISABLE TIMES



DEFINITIONS:

- C_L = Load capacitance: includes jig and probe capacitance.
- R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

- Pulse Generator for all pulses: Rate $\leq 10\text{MHz}$; $t_F \leq 2.5\text{ns}$; $t_R \leq 2.5\text{ns}$.
- Pulse Generator for all pulses: Rate $\leq 10\text{MHz}$; $t_F \leq 2\text{ns}$; $t_R \leq 2\text{ns}$.

NOTE:

- Diagram shown for input control Enable-LOW and input Control Disable-HIGH.

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open

ORDERING INFORMATION

IDT	XX	CBTLV	XXXX	X	
Temp. Range		Device Type		Package	
				PG	Thin Shrink Small Outline Package (SO14-3)
				Q	Quarter Small Outline Package (SO16-7)
				3126	Low-Voltage Quadruple Bus Switch
				74	-40°C to +85°C



CORPORATE HEADQUARTERS
2975 Stender Way
Santa Clara, CA 95054

for SALES:
800-345-7015 or 408-727-6116
fax: 408-492-8674
www.idt.com

for Tech Support:
logichelp@idt.com
(408) 654-6459